

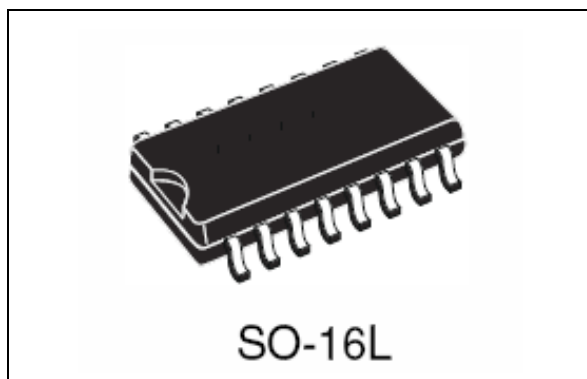
## Double channel high-side driver

### Features

| Type      | $R_{DS(on)}$        | $I_{OUT}$            | $V_{CC}$ |
|-----------|---------------------|----------------------|----------|
| VND830E-E | 65 m $\Omega^{(1)}$ | 9.5 A <sup>(1)</sup> | 36 V     |

1. Per each channel.

- Output current: 9.5 A
- CMOS compatible inputs
- On-state open-load detection
- Off-state open-load detection
- Output stuck to  $V_{CC}$  detection
- Open drain status outputs
- Undervoltage shutdown
- Overvoltage clamp
- Thermal shutdown
- Current and power limitation
- Very low standby current
- Protection against loss of ground and loss of  $V_{CC}$
- Reverse battery protection
- Very low electromagnetic susceptibility
- Optimized electromagnetic emission



### Description

The VND830E-E is a monolithic device made by using STMicroelectronics™ VIPower™ M0-3 technology. It is intended for driving resistive or inductive loads with one side connected to ground.

Active  $V_{CC}$  pin voltage clamp protects the device against low energy spikes (see ISO7637 transient compatibility table).

The device detects open-load condition both in on-state and off-state. Output shorted to  $V_{CC}$  is detected in the off-state.

Output current limitation protects the device in overload condition. In case of long duration overload, the device limits the dissipated power to safe level up to thermal shutdown intervention.

Thermal shutdown with automatic restart allows the device to recover normal operation as soon as fault condition disappears.

**Table 1. Device summary**

| Package | Order codes |               |
|---------|-------------|---------------|
|         | Tube        | Tape and reel |
| SO-16L  | VND830E-E   | VND830ETR-E   |

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1 Block diagram and pin description

Figure 1. Block diagram

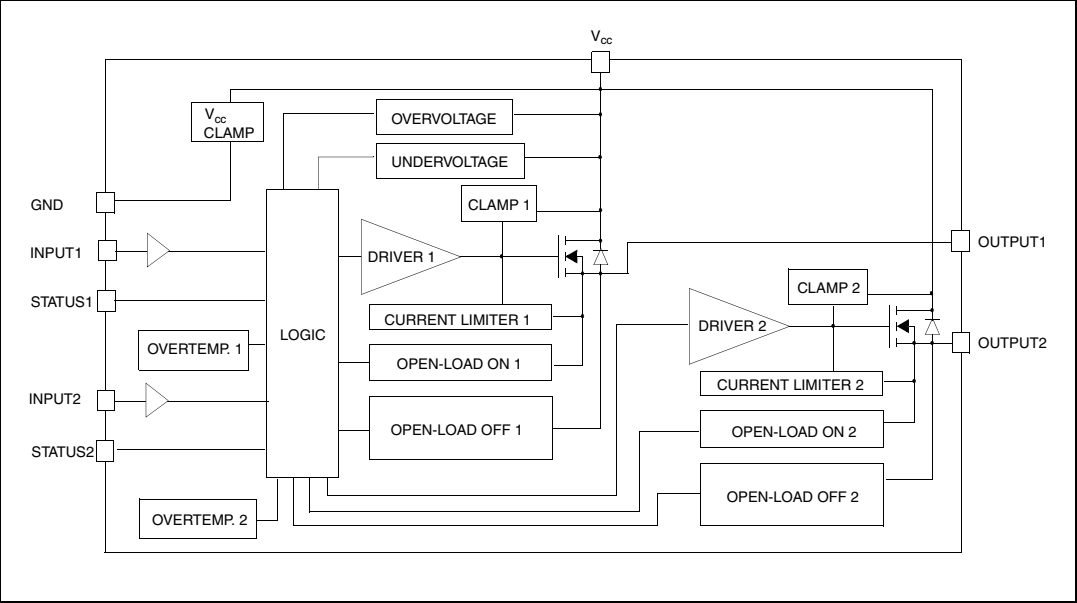


Figure 2. Configuration diagram (top view)

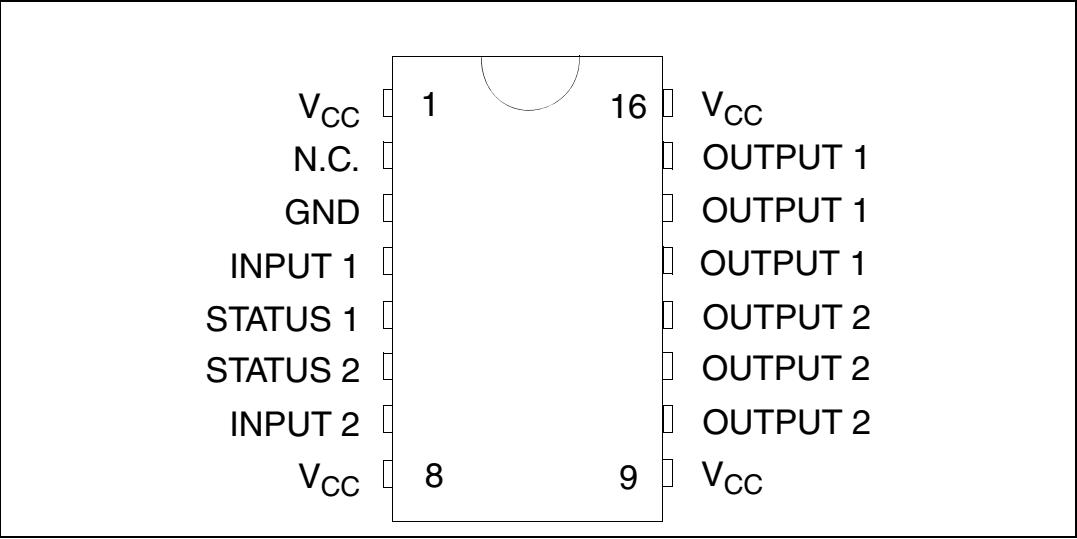


Table 2. Suggested connections for unused and not connected pins

| Connection / pin | Status | N.C. | Output | Input                  |
|------------------|--------|------|--------|------------------------|
| Floating         | X      | X    | X      | X                      |
| To ground        | -      | X    | -      | Through 10 KΩ resistor |

## 2 Electrical specifications

### 2.1 Absolute maximum ratings

Stressing the device above the rating listed in [Table 3](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality document.

**Table 3. Absolute maximum ratings**

| Symbol     | Parameter                                                                                                                                                                     | Value              | Unit             |
|------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|------------------|
| $V_{CC}$   | DC supply voltage                                                                                                                                                             | 41                 | V                |
| $-V_{CC}$  | Reverse DC supply voltage                                                                                                                                                     | - 0.3              | V                |
| $-I_{GND}$ | DC reverse ground pin current                                                                                                                                                 | - 200              | mA               |
| $I_{OUT}$  | DC output current                                                                                                                                                             | Internally limited | A                |
| $-I_{OUT}$ | Reverse DC output current                                                                                                                                                     | - 6                | A                |
| $I_{IN}$   | DC input current                                                                                                                                                              | +/- 10             | mA               |
| $I_{STAT}$ | DC status current                                                                                                                                                             | +/- 10             | mA               |
| $V_{ESD}$  | Electrostatic discharge (Human Body Model: $R = 1.5\text{ K}\Omega$ ; $C = 100\text{ pF}$ )                                                                                   |                    |                  |
|            | - INPUT                                                                                                                                                                       | 4000               | V                |
|            | - STATUS                                                                                                                                                                      | 4000               | V                |
|            | - OUTPUT                                                                                                                                                                      | 5000               | V                |
|            | - $V_{CC}$                                                                                                                                                                    | 5000               | V                |
| $E_{MAX}$  | Maximum switching energy<br>( $L = 0.45\text{ mH}$ ; $R_L = 0\text{ }\Omega$ ; $V_{bat} = 13.5\text{ V}$ ; $T_{jstart} = 150\text{ }^\circ\text{C}$ ; $I_L = 13.5\text{ A}$ ) | 57                 | mJ               |
| $P_{tot}$  | Power dissipation $T_C = 25\text{ }^\circ\text{C}$                                                                                                                            | 8.3                | W                |
| $T_j$      | Junction operating temperature                                                                                                                                                | Internally limited | $^\circ\text{C}$ |
| $T_C$      | Case operating temperature                                                                                                                                                    | - 40 to 150        | $^\circ\text{C}$ |
| $T_{stg}$  | Storage temperature                                                                                                                                                           | - 55 to 150        | $^\circ\text{C}$ |

## 2.2 Thermal data

**Table 4. Thermal data (per island)**

| Symbol         | Parameter                           | Value             |                   | Unit |
|----------------|-------------------------------------|-------------------|-------------------|------|
| $R_{thj-lead}$ | Thermal resistance junction-lead    | 15                |                   | °C/W |
| $R_{thj-amb}$  | Thermal resistance junction-ambient | 65 <sup>(1)</sup> | 47 <sup>(2)</sup> | °C/W |

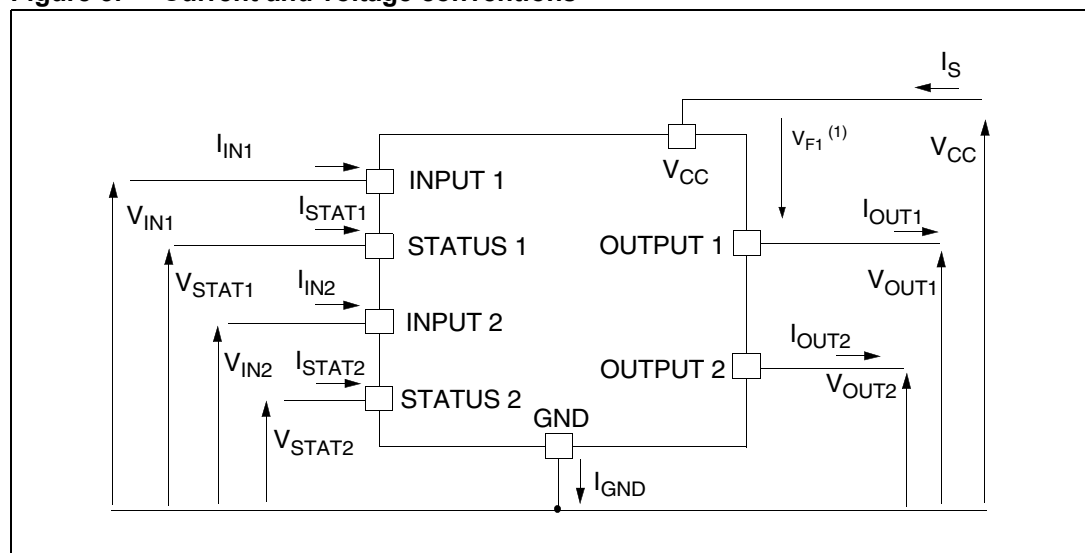
1. When mounted on a standard single-sided FR-4 board with 0.5 cm<sup>2</sup> of Cu (at least 35 µm thick) connected to all  $V_{CC}$  pins. Horizontal mounting and no artificial air flow.
2. When mounted on a standard single-sided FR-4 board with 6 cm<sup>2</sup> of Cu (at least 35 µm thick) connected to all  $V_{CC}$  pins. Horizontal mounting and no artificial air flow.

## 2.3 Electrical characteristics

Values specified in this section are for  $8\text{ V} < V_{CC} < 36\text{ V}$ ;  $-40\text{ °C} < T_j < 150\text{ °C}$ , unless otherwise stated.

(Per each channel)

**Figure 3. Current and voltage conventions**



1.  $V_{Fn} = V_{CCn} - V_{OUTn}$  during reverse battery condition.

**Table 5. Power outputs**

| Symbol    | Parameter                | Test conditions                                                                                 | Min. | Typ. | Max.      | Unit     |
|-----------|--------------------------|-------------------------------------------------------------------------------------------------|------|------|-----------|----------|
| $V_{CC}$  | Operating supply voltage |                                                                                                 | 5.5  | 13   | 36        | V        |
| $V_{USD}$ | Undervoltage shutdown    |                                                                                                 | 3    | 4    | 5.5       | V        |
| $V_{OV}$  | Overvoltage shutdown     |                                                                                                 | 36   |      |           | V        |
| $R_{ON}$  | On-state resistance      | $I_{OUT} = 2\text{ A}$ ; $T_j = 25\text{ °C}$<br>$I_{OUT} = 2\text{ A}$ ; $V_{CC} > 8\text{ V}$ |      |      | 65<br>130 | mΩ<br>mΩ |

**Table 5. Power outputs (continued)**

| Symbol        | Parameter                | Test conditions                                                                                   | Min. | Typ. | Max. | Unit          |
|---------------|--------------------------|---------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $I_S$         | Supply current           | Off-state; $V_{CC} = 13\text{ V}$ ;<br>$V_{IN} = V_{OUT} = 0\text{ V}$                            |      | 12   | 40   | $\mu\text{A}$ |
|               |                          | Off-state; $V_{CC} = 13\text{ V}$ ;<br>$V_{IN} = V_{OUT} = 0\text{ V}$ ; $T_j = 25^\circ\text{C}$ |      | 12   | 25   | $\mu\text{A}$ |
|               |                          | On-state; $V_{CC} = 13\text{ V}$ ;<br>$V_{IN} = 5\text{ V}$ ; $I_{OUT} = 0\text{ A}$              |      | 5    | 7    | $\text{mA}$   |
| $I_{L(off1)}$ | Off-state output current | $V_{IN} = V_{OUT} = 0\text{ V}$                                                                   | 0    |      | 50   | $\mu\text{A}$ |
| $I_{L(off2)}$ | Off-state output current | $V_{IN} = 0\text{ V}$ ; $V_{OUT} = 3.5\text{ V}$                                                  | -75  |      | 0    | $\mu\text{A}$ |
| $I_{L(off3)}$ | Off-state output current | $V_{IN} = V_{OUT} = 0\text{ V}$ ; $V_{CC} = 13\text{ V}$ ;<br>$T_j = 125^\circ\text{C}$           |      |      | 5    | $\mu\text{A}$ |
| $I_{L(off4)}$ | Off-state output current | $V_{IN} = V_{OUT} = 0\text{ V}$ ; $V_{CC} = 13\text{ V}$ ;<br>$T_j = 25^\circ\text{C}$            |      |      | 3    | $\mu\text{A}$ |

**Table 6. Switching ( $V_{CC} = 13\text{ V}$ )**

| Symbol                | Parameter              | Test conditions                                                                | Min. | Typ.                          | Max. | Unit                   |
|-----------------------|------------------------|--------------------------------------------------------------------------------|------|-------------------------------|------|------------------------|
| $t_{d(on)}$           | Turn-on delay time     | $R_L = 6.5\ \Omega$ from $V_{IN}$ rising edge to $V_{OUT} = 1.3\text{ V}$      | -    | 50                            | -    | $\mu\text{s}$          |
| $t_{d(off)}$          | Turn-off delay time    | $R_L = 6.5\ \Omega$ from $V_{IN}$ falling edge to $V_{OUT} = 11.7\text{ V}$    | -    | 50                            | -    | $\mu\text{s}$          |
| $dV_{OUT}/dt_{(on)}$  | Turn-on voltage slope  | $R_L = 6.5\ \Omega$ from $V_{OUT} = 1.3\text{ V}$ to $V_{OUT} = 10.4\text{ V}$ | -    | See <a href="#">Figure 21</a> | -    | $\text{V}/\mu\text{s}$ |
| $dV_{OUT}/dt_{(off)}$ | Turn-off voltage slope | $R_L = 6.5\ \Omega$ from $V_{OUT} = 11.7\text{ V}$ to $V_{OUT} = 1.3\text{ V}$ | -    | See <a href="#">Figure 22</a> | -    | $\text{V}/\mu\text{s}$ |

**Table 7. Logic input**

| Symbol        | Parameter                | Test conditions          | Min. | Typ. | Max. | Unit          |
|---------------|--------------------------|--------------------------|------|------|------|---------------|
| $V_{IL}$      | Input low level          |                          |      |      | 1.25 | $\text{V}$    |
| $I_{IL}$      | Low level input current  | $V_{IN} = 1.25\text{ V}$ | 1    |      |      | $\mu\text{A}$ |
| $V_{IH}$      | Input high level         |                          | 3.25 |      |      | $\text{V}$    |
| $I_{IH}$      | High level input current | $V_{IN} = 3.25\text{ V}$ |      |      | 10   | $\mu\text{A}$ |
| $V_{I(hyst)}$ | Input hysteresis voltage |                          | 0.5  |      |      | $\text{V}$    |
| $V_{ICL}$     | Input clamp voltage      | $I_{IN} = 1\text{ mA}$   | 6    | 6.8  | 8    | $\text{V}$    |
|               |                          | $I_{IN} = -1\text{ mA}$  |      | -0.7 |      | $\text{V}$    |



**Table 8.  $V_{CC}$  - output diode**

| Symbol | Parameter          | Test conditions                                                 | Min. | Typ. | Max. | Unit |
|--------|--------------------|-----------------------------------------------------------------|------|------|------|------|
| $V_F$  | Forward on voltage | $-I_{OUT} = 1.2 \text{ A}$ ; $T_j = 150 \text{ }^\circ\text{C}$ | -    | -    | 0.6  | V    |

**Table 9. Status pin**

| Symbol      | Parameter                    | Test conditions                                         | Min. | Typ.         | Max. | Unit          |
|-------------|------------------------------|---------------------------------------------------------|------|--------------|------|---------------|
| $V_{STAT}$  | Status low output voltage    | $I_{STAT} = 1.6 \text{ mA}$                             |      |              | 0.5  | V             |
| $I_{LSTAT}$ | Status leakage current       | Normal operation; $V_{STAT} = 5 \text{ V}$              |      |              | 10   | $\mu\text{A}$ |
| $C_{STAT}$  | Status pin Input capacitance | Normal operation; $V_{STAT} = 5 \text{ V}$              |      |              | 100  | pF            |
| $V_{SCL}$   | Status clamp voltage         | $I_{STAT} = 1 \text{ mA}$<br>$I_{STAT} = -1 \text{ mA}$ | 6    | 6.8<br>- 0.7 | 8    | V<br>V        |

**Table 10. Protections<sup>(1)</sup>**

| Symbol      | Parameter                           | Test conditions                                                    | Min.        | Typ.        | Max.        | Unit             |
|-------------|-------------------------------------|--------------------------------------------------------------------|-------------|-------------|-------------|------------------|
| $T_{TSD}$   | Shutdown temperature                |                                                                    | 150         | 175         | 200         | $^\circ\text{C}$ |
| $T_R$       | Reset temperature                   |                                                                    | 135         |             |             | $^\circ\text{C}$ |
| $T_{hyst}$  | Thermal hysteresis                  |                                                                    | 7           | 15          |             | $^\circ\text{C}$ |
| $t_{SDL}$   | Status delay in overload conditions | $T_j > T_{TSD}$                                                    |             |             | 20          | $\mu\text{s}$    |
| $I_{lim}$   | Current limitation                  | $V_{CC} = 13 \text{ V}$<br>$5.5 \text{ V} < V_{CC} < 36 \text{ V}$ | 9.5         | 13.5        | 18<br>18    | A<br>A           |
| $V_{demag}$ | Turn-off output clamp voltage       | $I_{OUT} = 2 \text{ A}$ ; $L = 6 \text{ mH}$                       | $V_{CC}-41$ | $V_{CC}-48$ | $V_{CC}-55$ | V                |

1. To ensure long term reliability under heavy overload or short circuit conditions, protection and related diagnostic signals must be used together with a proper software strategy. If the device is subjected to abnormal conditions, this software must limit the duration and number of activation cycles.

**Table 11. Open-load detection**

| Symbol         | Parameter                                       | Test conditions         | Min. | Typ. | Max. | Unit          |
|----------------|-------------------------------------------------|-------------------------|------|------|------|---------------|
| $I_{OL}$       | Open-load on-state detection threshold          | $V_{IN} = 5 \text{ V}$  | 50   | 115  | 200  | mA            |
| $t_{DOL(on)}$  | Open-load on-state detection delay              | $I_{OUT} = 0 \text{ A}$ |      |      | 200  | $\mu\text{s}$ |
| $V_{OL}$       | Open-load off-state voltage detection threshold | $V_{IN} = 0 \text{ V}$  | 1.5  | 2.9  | 3.5  | V             |
| $t_{DOL(off)}$ | Open-load detection delay at turn-off           |                         |      |      | 1000 | $\mu\text{s}$ |

Figure 4. Status timings

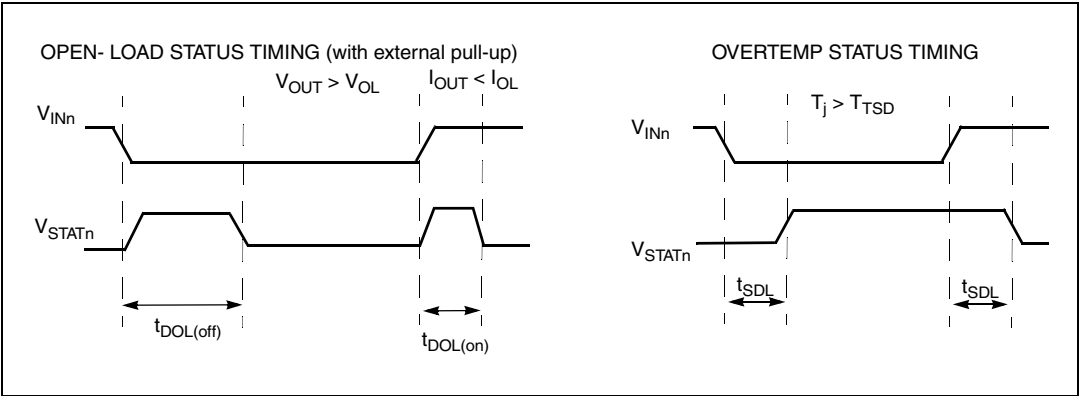


Figure 5. Switching time waveforms

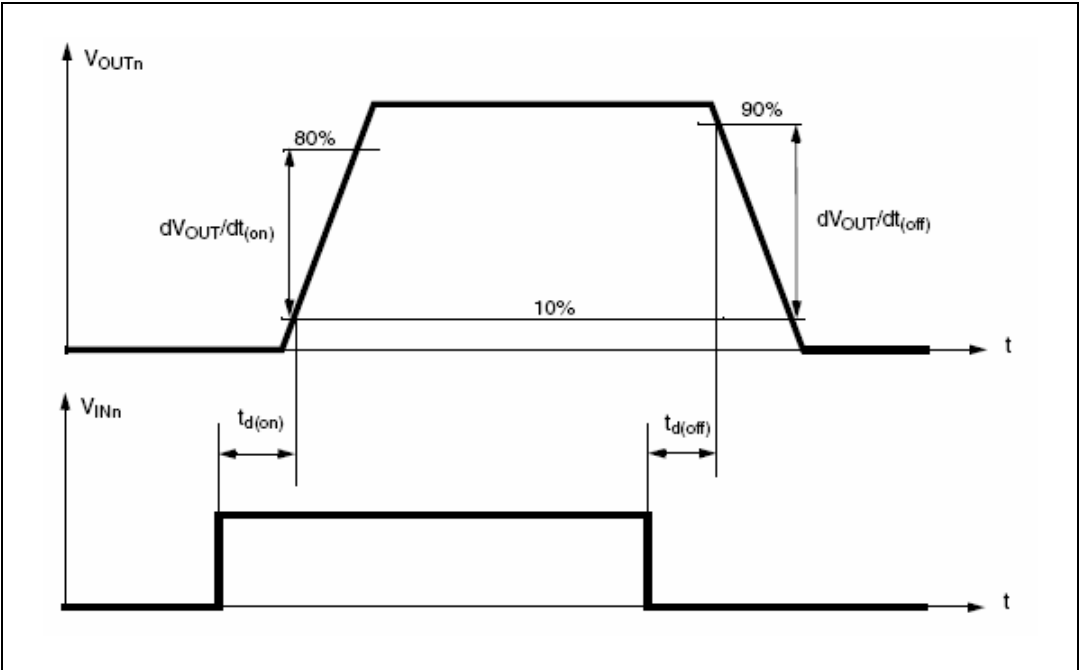


Table 12. Truth table

| Conditions         | Input <sub>n</sub> | Output <sub>n</sub> | Status <sub>n</sub>                                                              |
|--------------------|--------------------|---------------------|----------------------------------------------------------------------------------|
| Normal operation   | L                  | L                   | H                                                                                |
|                    | H                  | H                   | H                                                                                |
| Current limitation | L                  | L                   | H                                                                                |
|                    | H                  | X                   | (T <sub>j</sub> < T <sub>TSD</sub> ) H<br>(T <sub>j</sub> > T <sub>TSD</sub> ) L |
| Overtemperature    | L                  | L                   | H                                                                                |
|                    | H                  | L                   | L                                                                                |
| Undervoltage       | L                  | L                   | X                                                                                |
|                    | H                  | L                   | X                                                                                |

Table 12. Truth table (continued)

| Conditions                        | Input <sub>n</sub> | Output <sub>n</sub> | Status <sub>n</sub> |
|-----------------------------------|--------------------|---------------------|---------------------|
| Overvoltage                       | L                  | L                   | H                   |
|                                   | H                  | L                   | H                   |
| Output voltage > V <sub>OLn</sub> | L                  | H                   | L                   |
|                                   | H                  | H                   | H                   |
| Output current < I <sub>OLn</sub> | L                  | L                   | H                   |
|                                   | H                  | H                   | L                   |

Table 13. Electrical transient requirements on V<sub>CC</sub> pin (part 1)

| ISO T/R<br>7637/1<br>test pulse | Test levels |         |         |         |                      |
|---------------------------------|-------------|---------|---------|---------|----------------------|
|                                 | I           | II      | III     | IV      | Delays and impedance |
| 1                               | -25 V       | -50 V   | -75 V   | -100 V  | 2 ms, 10 Ω           |
| 2                               | +25 V       | +50 V   | +75 V   | +100 V  | 0.2 ms, 10 Ω         |
| 3a                              | -25 V       | -50 V   | -100 V  | -150 V  | 0.1 μs, 50 Ω         |
| 3b                              | +25 V       | +50 V   | +75 V   | +100 V  | 0.1 μs, 50 Ω         |
| 4                               | -4 V        | -5 V    | -6 V    | -7 V    | 100 ms, 0.01 Ω       |
| 5                               | +26.5 V     | +46.5 V | +66.5 V | +86.5 V | 400 ms, 2 Ω          |

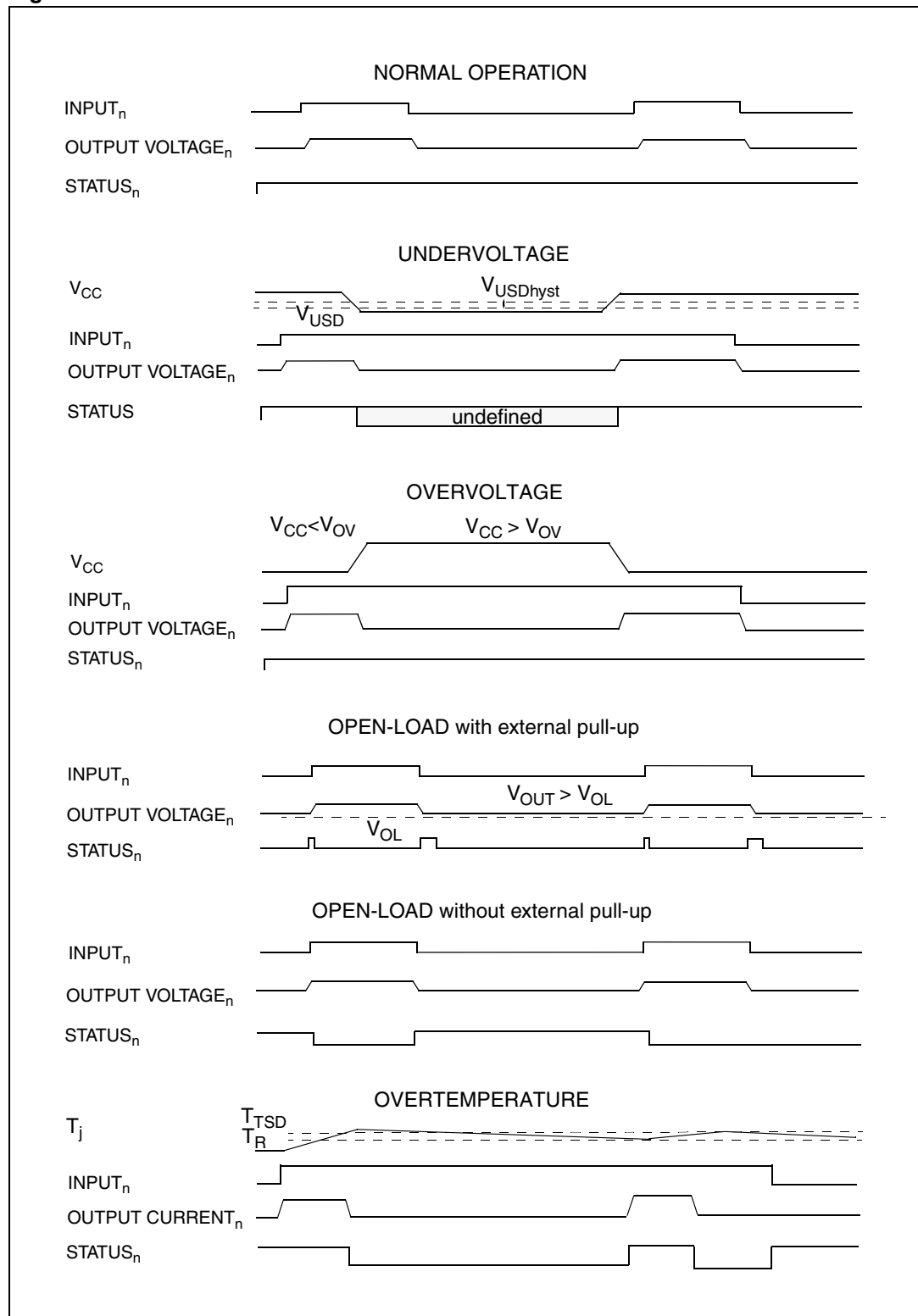
Table 14. Electrical transient requirements on V<sub>CC</sub> pin (part 2)

| ISO T/R<br>7637/1<br>test pulse | Test levels results |    |     |    |
|---------------------------------|---------------------|----|-----|----|
|                                 | I                   | II | III | IV |
| 1                               | C                   | C  | C   | C  |
| 2                               | C                   | C  | C   | C  |
| 3a                              | C                   | C  | C   | C  |
| 3b                              | C                   | C  | C   | C  |
| 4                               | C                   | C  | C   | C  |
| 5                               | C                   | E  | E   | E  |

Table 15. Electrical transient requirements on V<sub>CC</sub> pin (part 3)

| Class | Contents                                                                                                                                                                |
|-------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| C     | All functions of the device are performed as designed after exposure to disturbance.                                                                                    |
| E     | One or more functions of the device is not performed as designed after exposure to disturbance and cannot be returned to proper operation without replacing the device. |

Figure 6. Waveforms



2.4 Electrical characteristics curves

Figure 7. Off-state output current

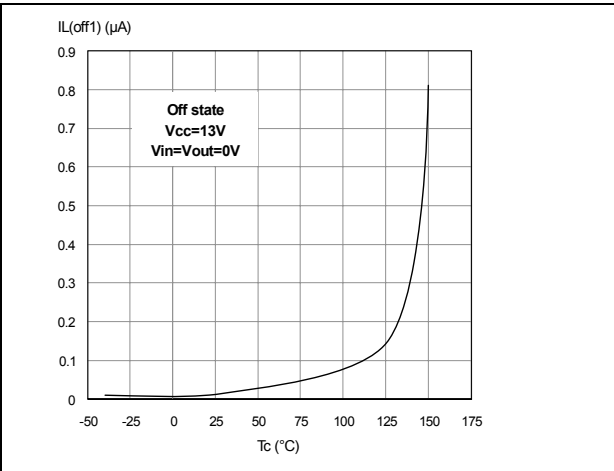


Figure 8. High level input current

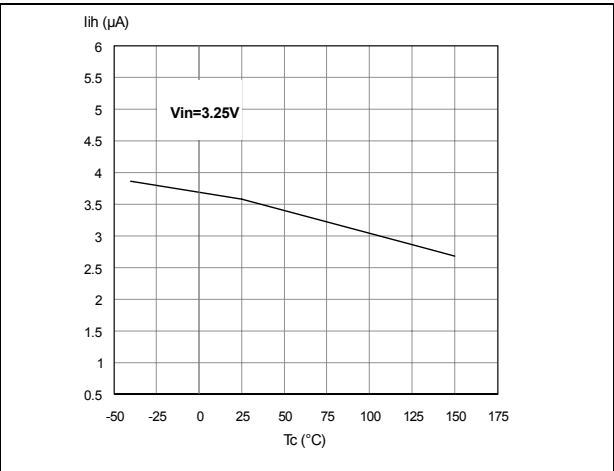


Figure 9. Input clamp voltage

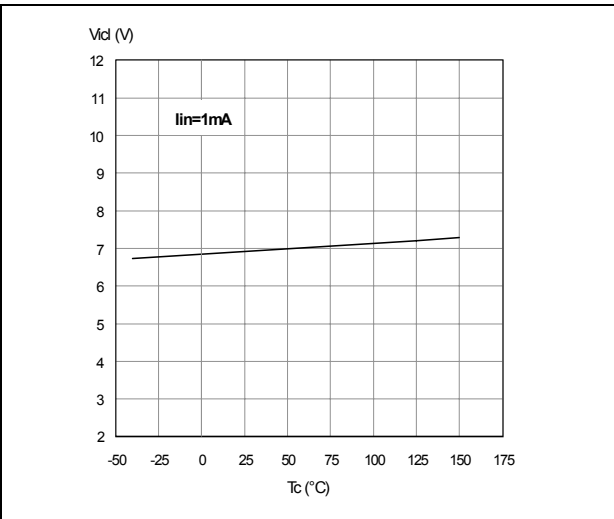


Figure 10. Status leakage current

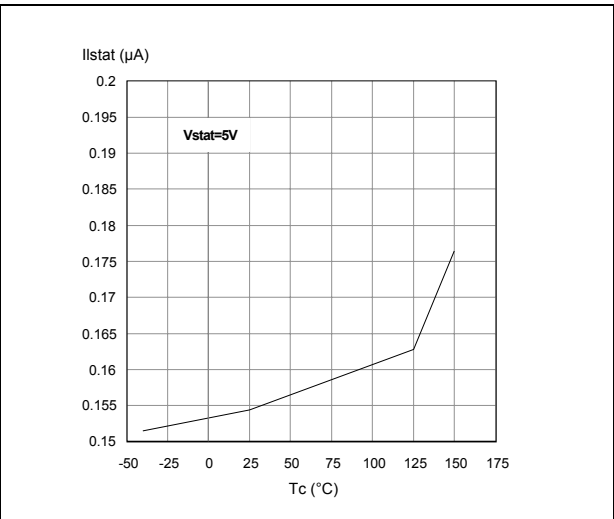


Figure 11. Status low output voltage

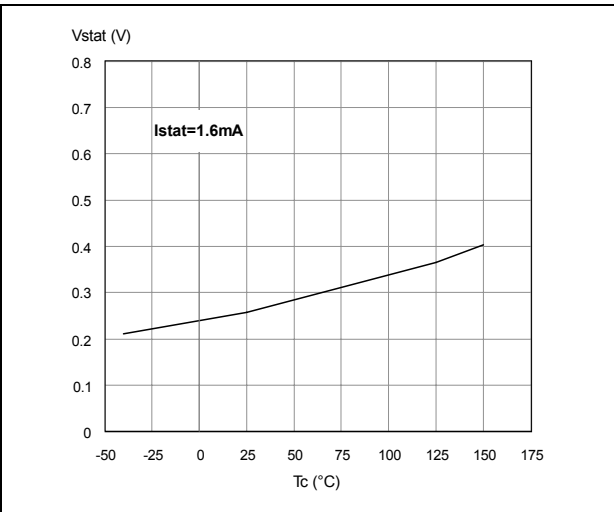


Figure 12. Status clamp voltage

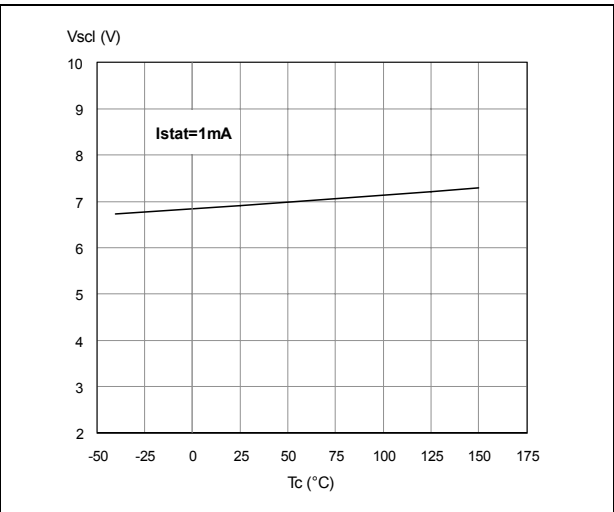


Figure 13. On-state resistance vs  $T_{case}$

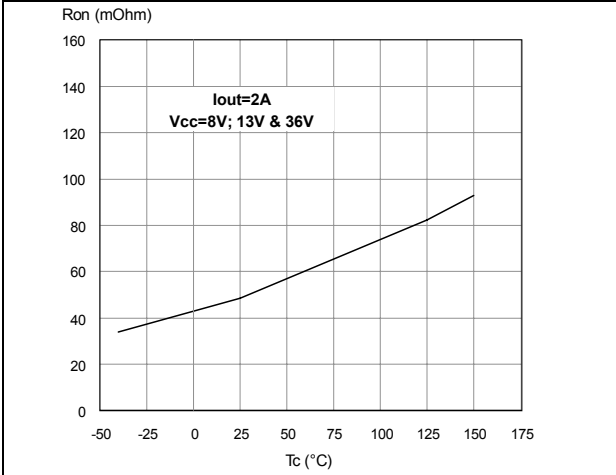


Figure 14. On-state resistance vs  $V_{CC}$

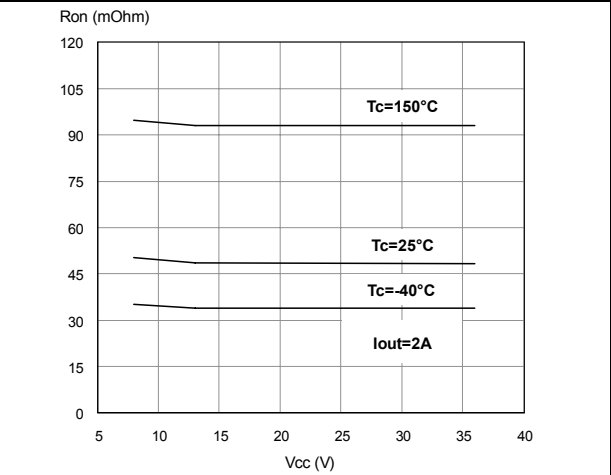


Figure 15. Open-load on-state detection threshold

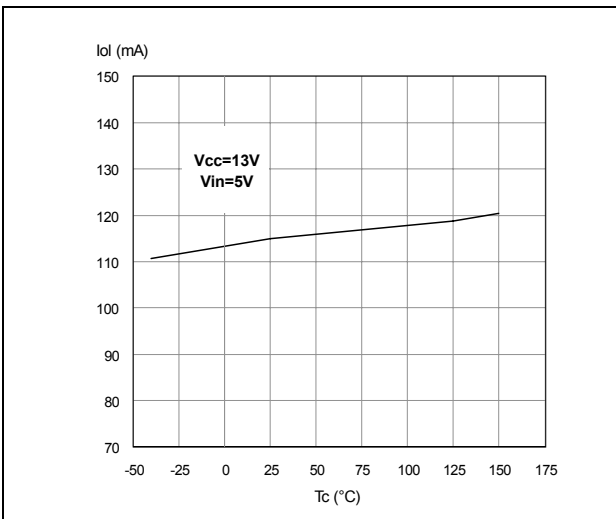


Figure 16. Open-load off-state detection threshold

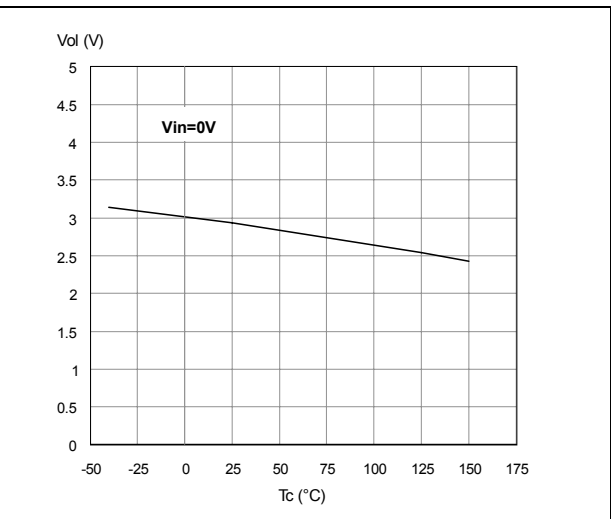


Figure 17. Input high level

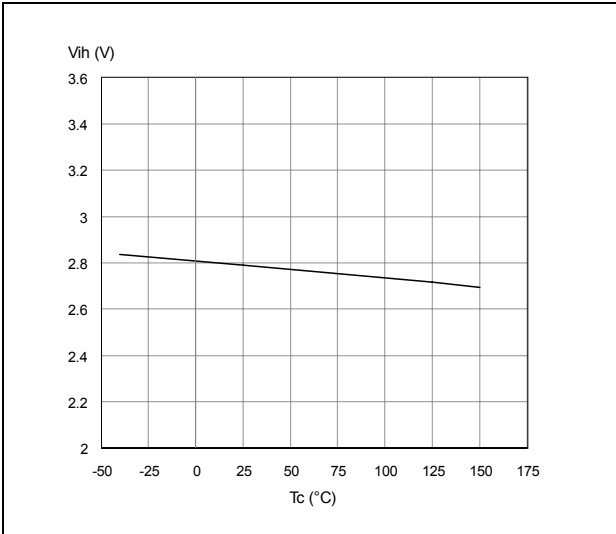


Figure 18. Input low level

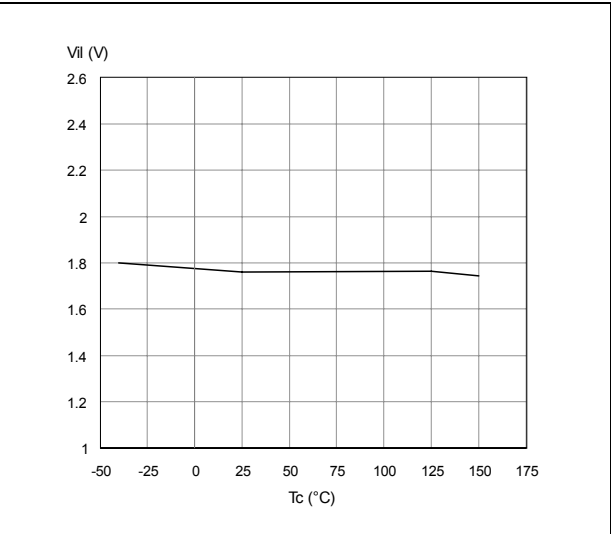


Figure 19. Input hysteresis voltage

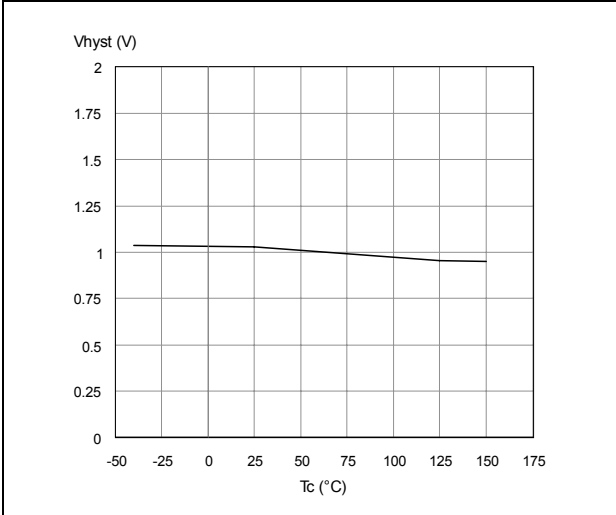


Figure 20. Overvoltage shutdown

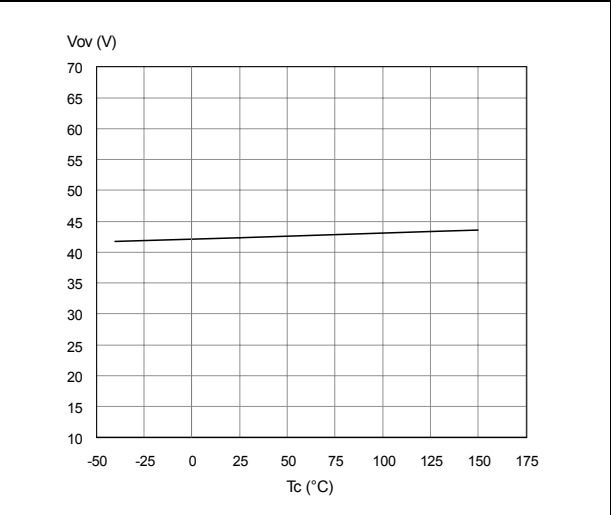


Figure 21. Turn-on voltage slope

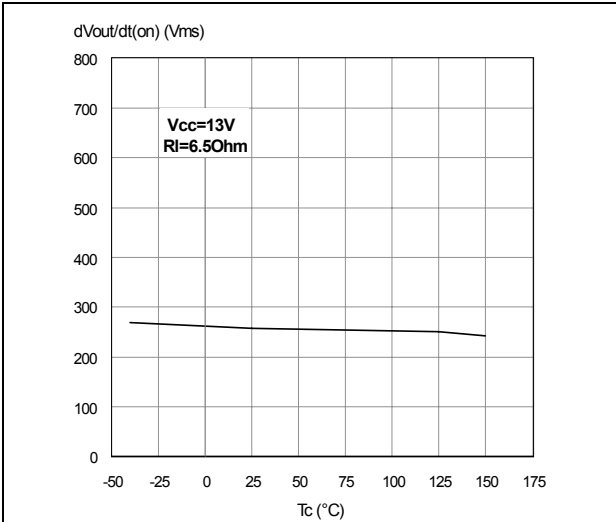


Figure 22. Turn-off voltage slope

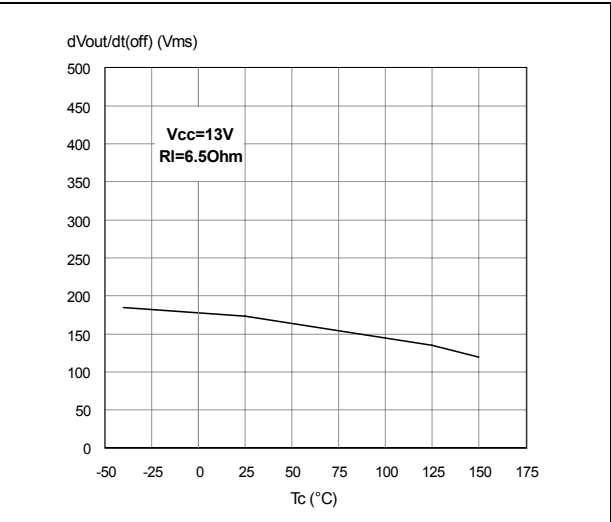


Figure 23.  $I_{LIM}$  vs  $T_{case}$

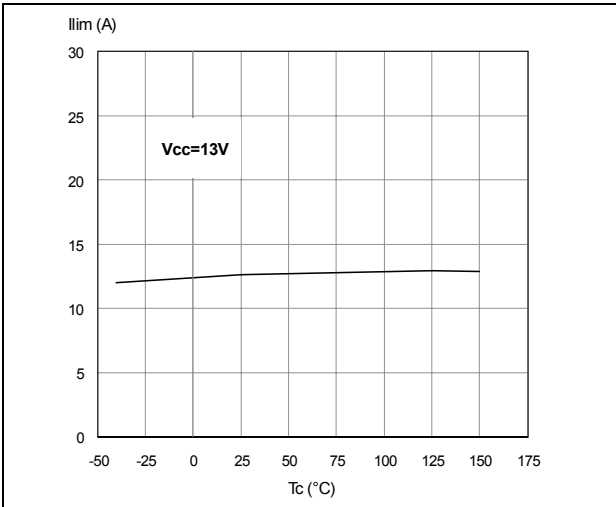
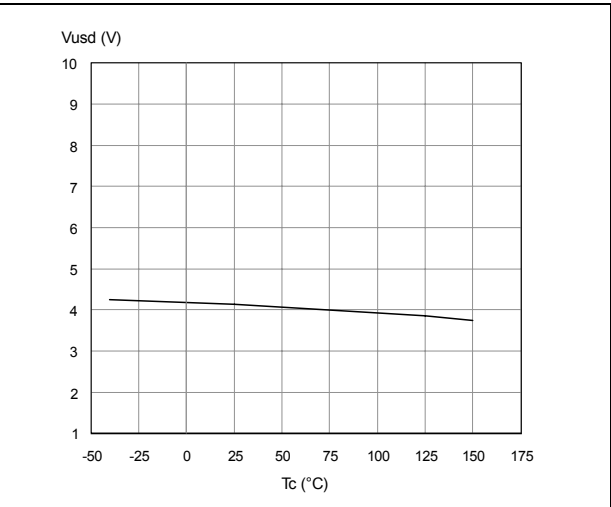
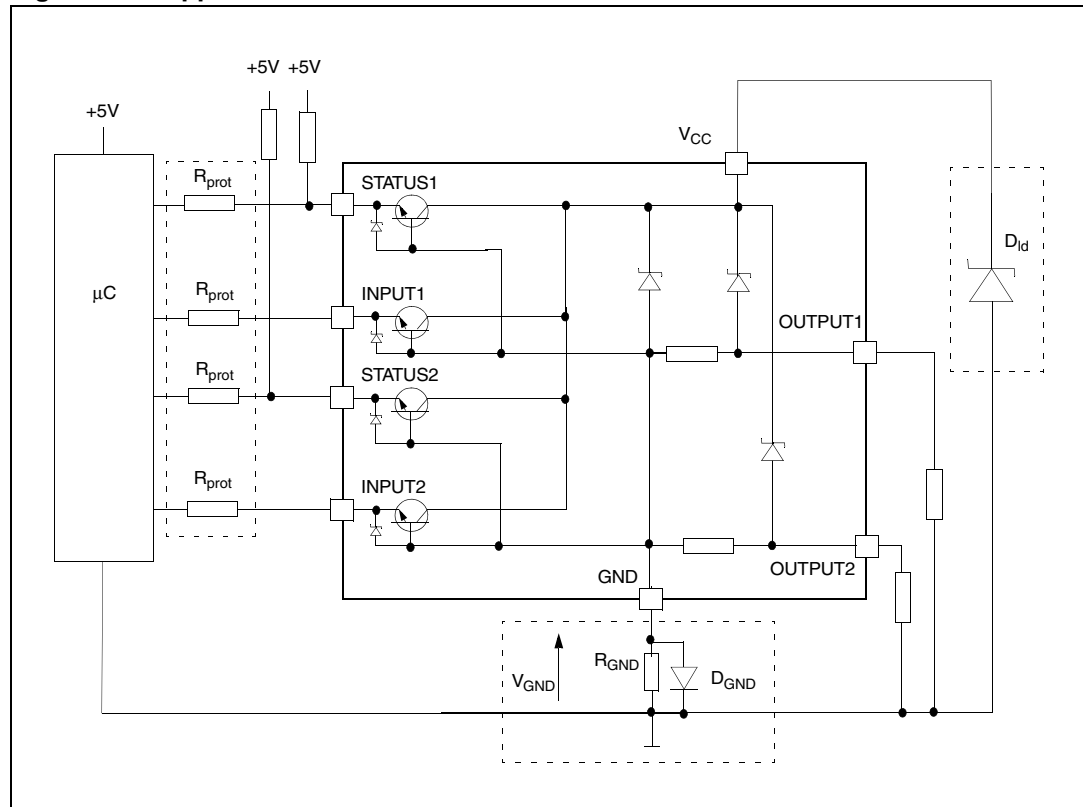


Figure 24. Undervoltage shutdown



### 3 Application information

Figure 25. Application schematic



#### 3.1 GND protection network against reverse battery

This section provides two solutions for implementing a ground protection network against reverse battery.

##### 3.1.1 Solution 1: a resistor in the ground line ( $R_{GND}$ only)

This can be used with any type of load.

The following shows how to dimension the  $R_{GND}$  resistor:

1.  $R_{GND} \leq 600 \text{ mV} / (I_{S(on)max})$
2.  $R_{GND} \geq (-V_{CC}) / (-I_{GND})$

where  $-I_{GND}$  is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device's datasheet.

Power dissipation in  $R_{GND}$  (when  $V_{CC} < 0$  during reverse battery situations) is:

$$P_D = (-V_{CC})^2 / R_{GND}$$

This resistor can be shared amongst several different HSD. Please note that the value of this resistor should be calculated with formula (1) where  $I_{S(on)max}$  becomes the sum of the maximum on-state currents of the different devices.



Please note that, if the microprocessor ground is not common with the device ground, then the  $R_{GND}$  produces a shift ( $I_{S(on)max} * R_{GND}$ ) in the input thresholds and the status output values. This shift varies depending on how many devices are ON in the case of several high-side drivers sharing the same  $R_{GND}$ .

If the calculated power dissipation requires the use of a large resistor, or several devices have to share the same resistor, then ST suggests using [Section 3.1.2](#) described below.

### 3.1.2 Solution 2: a diode ( $D_{GND}$ ) in the ground line

A resistor ( $R_{GND} = 1\text{ k}\Omega$ ) should be inserted in parallel to  $D_{GND}$  if the device is driving an inductive load. This small signal diode can be safely shared amongst several different HSD. Also in this case, the presence of the ground network produce a shift ( $\sim 600\text{ mV}$ ) in the input threshold and the status output values if the microprocessor ground is not common with the device ground. This shift does not vary if more than one HSD shares the same diode/resistor network. Series resistor in INPUT and STATUS lines are also required to prevent that, during battery voltage transient, the current exceeds the absolute maximum rating. Safest configuration for unused INPUT and STATUS pin is to leave them unconnected.

## 3.2 Load dump protection

$D_{ld}$  is necessary (Voltage Transient Suppressor) if the load dump peak voltage exceeds the  $V_{CC}$  maximum DC rating. The same applies if the device is subjected to transients on the  $V_{CC}$  line that are greater than those shown in [Table 13](#).

## 3.3 MCU I/O protection

If a ground protection network is used and negative transients are present on the  $V_{CC}$  line, the control pins are pulled negative. ST suggests to insert a resistor ( $R_{prot}$ ) in line to prevent the microcontroller I/O pins from latching up.

The value of these resistors is a compromise between the leakage current of microcontroller and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of microcontroller I/Os:

$$-V_{CCpeak} / I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IHmax}$$

### Example

For the following conditions:

$$V_{CCpeak} = -100\text{ V}$$

$$I_{latchup} \geq 20\text{ mA}$$

$$V_{OH\mu C} \geq 4.5\text{ V}$$

$$5\text{ k}\Omega \leq R_{prot} \leq 65\text{ k}\Omega$$

The recommended values are:

$$R_{prot} = 10\text{ k}\Omega$$

### 3.4 Open-load detection in off-state

Off-state open-load detection requires an external pull-up resistor ( $R_{PU}$ ) connected between OUTPUT pin and a positive supply voltage ( $V_{PU}$ ) like the +5 V line used to supply the microprocessor.

The external resistor has to be selected according to the following requirements:

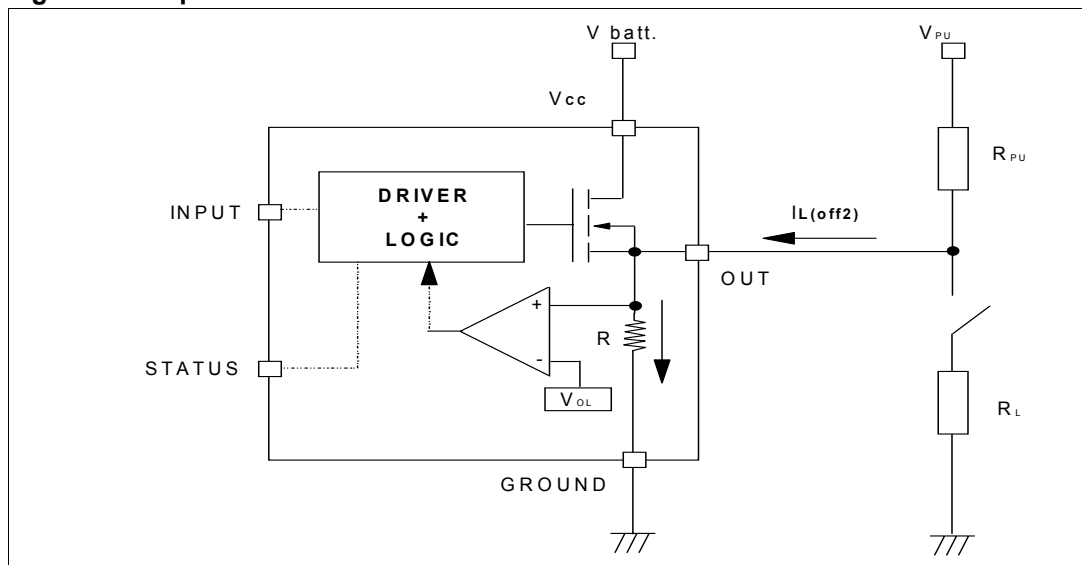
1. No false open-load indication when load is connected: in this case it needs to avoid  $V_{OUT}$  to be higher than  $V_{OLmin}$ ; this results in the following condition  

$$V_{OUT} = (V_{PU} / (R_L + R_{PU})) R_L < V_{OLmin}.$$
2. No misdetection when load is disconnected: in this case the  $V_{OUT}$  has to be higher than  $V_{OLmax}$ ; this results in the following condition  $R_{PU} < (V_{PU} - V_{OLmax}) / I_{L(off2)}.$

Because  $I_{S(OFF)}$  may significantly increase if  $V_{out}$  is pulled high (up to several mA), the pull-up resistor  $R_{PU}$  should be connected to a supply that is switched OFF when the module is in standby.

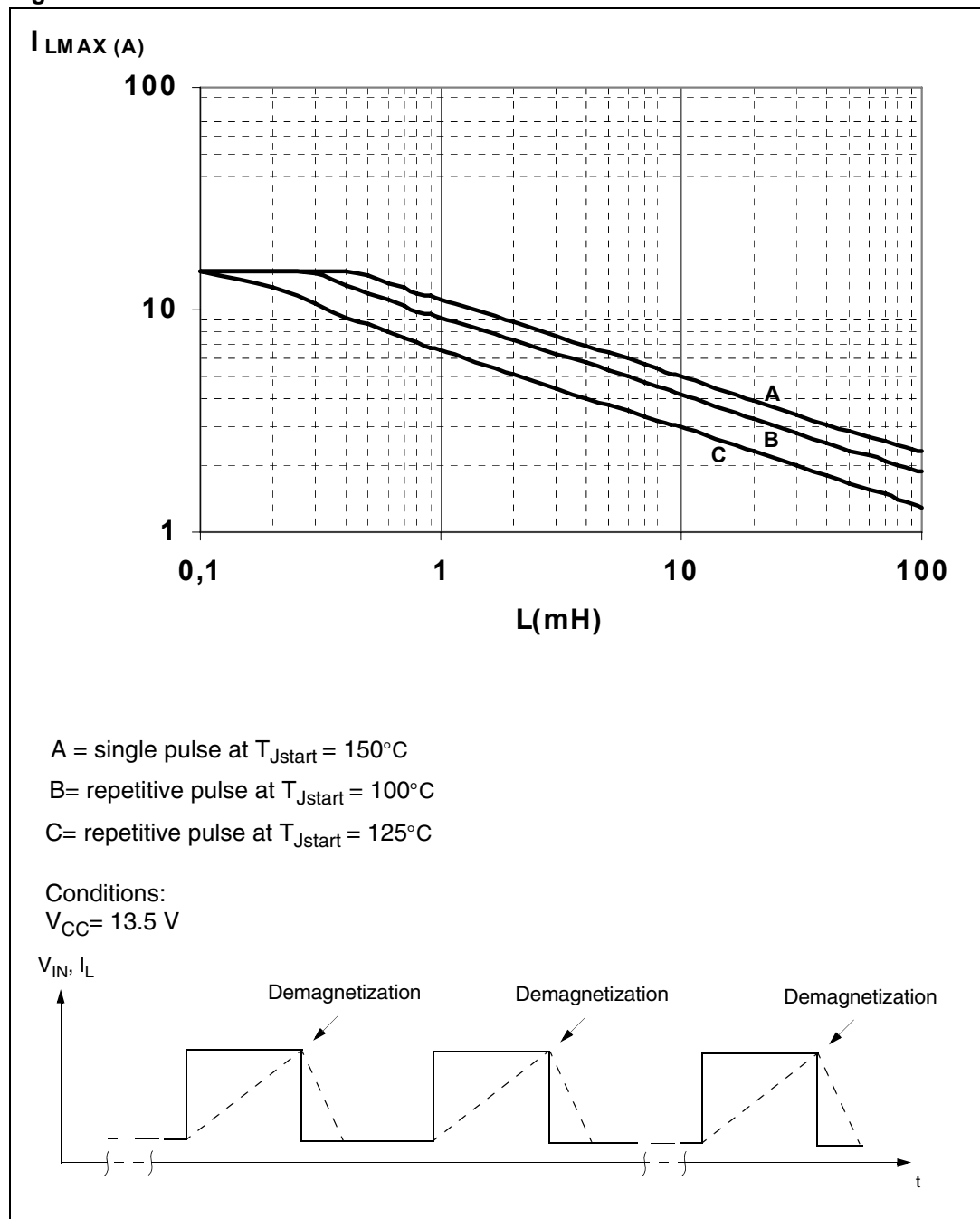
The values of  $V_{OLmin}$ ,  $V_{OLmax}$  and  $I_{L(off2)}$  are available in [Chapter 2: Electrical specifications](#).

**Figure 26. Open-load detection in off-state**



### 3.5 Maximum demagnetization energy

Figure 27. Maximum turn-off current versus load inductance



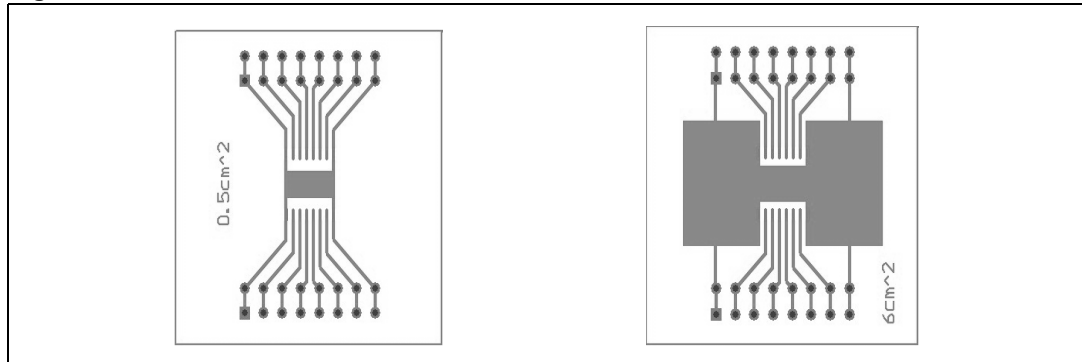
Note: Values are generated with  $RL = 0\ \Omega$ .

In case of repetitive pulses,  $T_{Jstart}$  (at beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves B and C.

## 4 Package and PCB thermal data

### 4.1 SO-16L thermal data

Figure 28. SO-16L PC board<sup>(1)</sup>



1. Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB FR4 area = 41 mm x 48 mm, PCB thickness = 2 mm, Cu thickness = 35  $\mu$ m, Copper areas: 0.5 cm<sup>2</sup>, 6 cm<sup>2</sup>).

Figure 29.  $R_{thj-amb}$  vs PCB copper area in open box free air condition

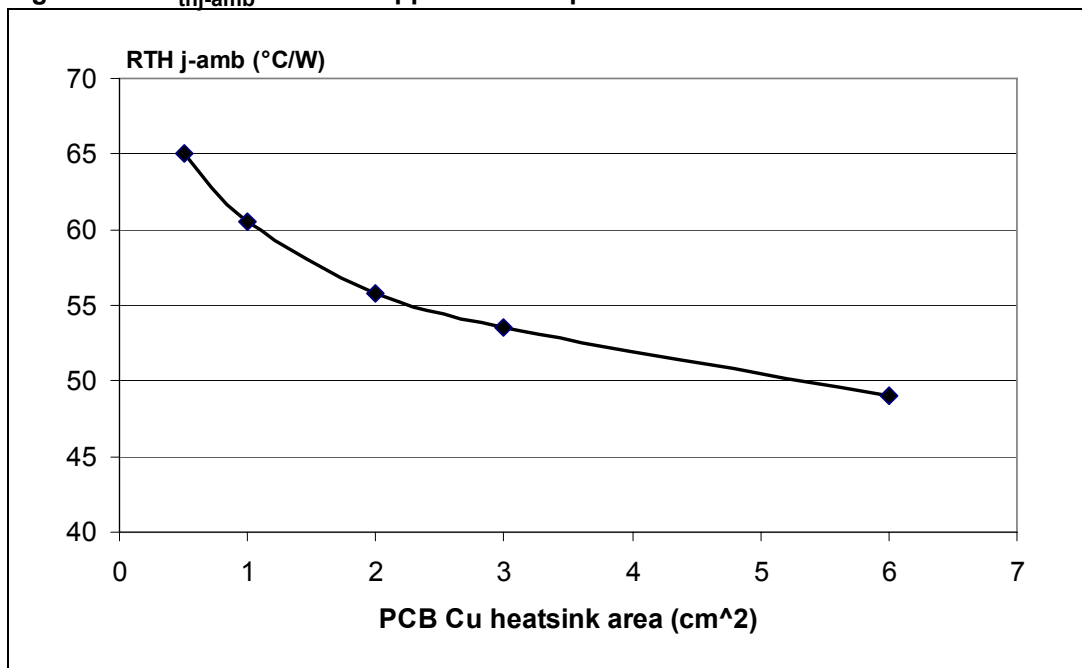
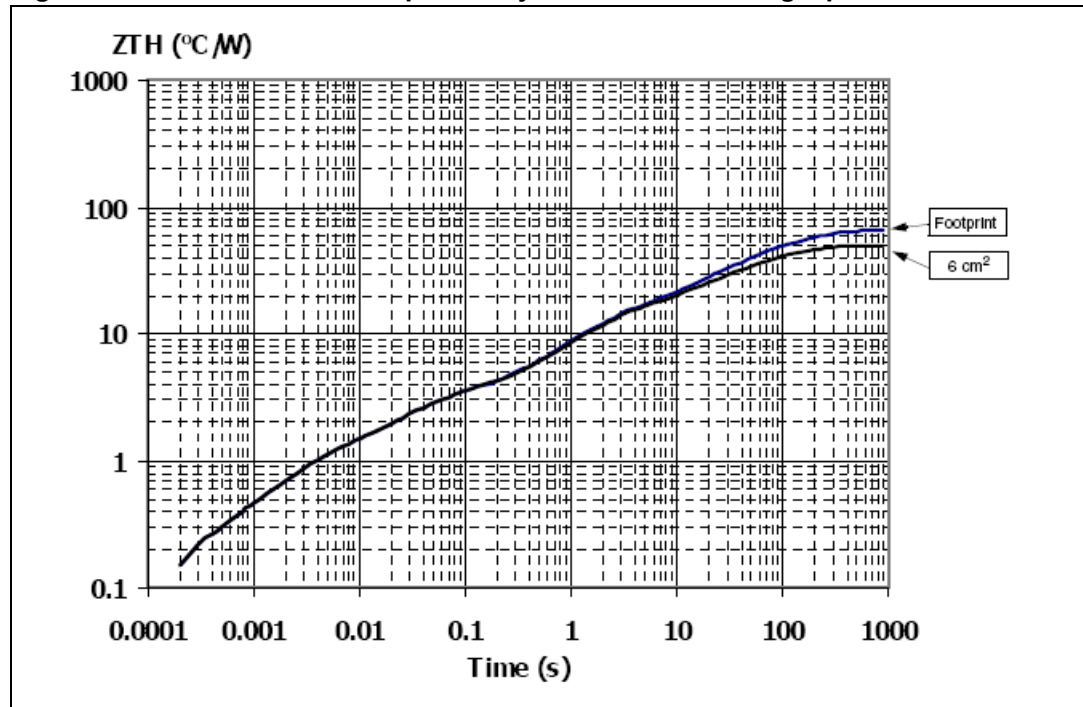


Figure 30. SO-16 L thermal impedance junction ambient single pulse



Equation 1: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

$$\text{where } \delta = t_p / T$$

Figure 31. Thermal fitting model of a quad channel HSD in SO-16L

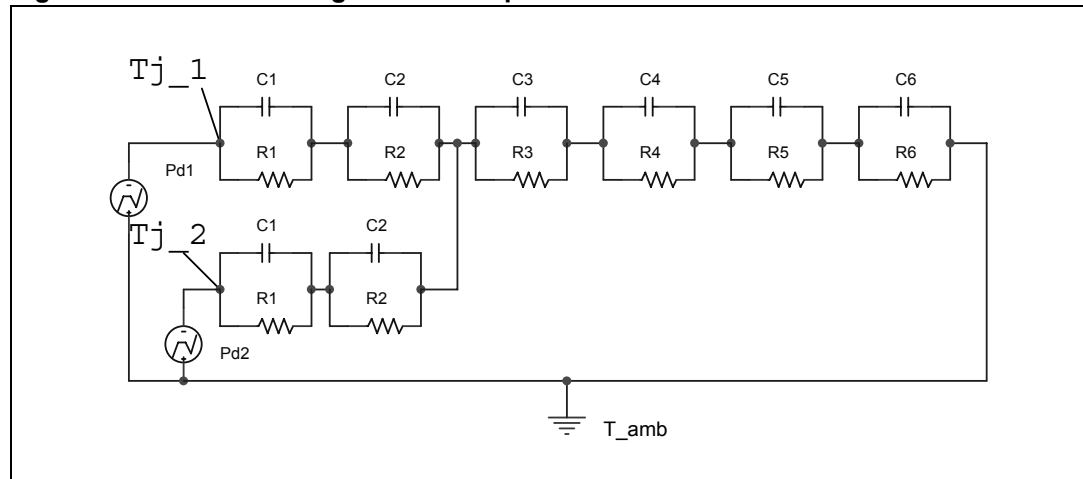


Table 16. Thermal parameters

| Area/ island (cm <sup>2</sup> ) | Footprint | 6  |
|---------------------------------|-----------|----|
| R1 (°C/W)                       | 0.15      |    |
| R2 (°C/W)                       | 0.7       |    |
| R3 (°C/W)                       | 2         |    |
| R4 (°C/W)                       | 10        |    |
| R5 (°C/W)                       | 15        |    |
| R6 (°C/W)                       | 37        | 22 |
| C1 (W.s/°C)                     | 0.0005    |    |
| C2 (W.s/°C)                     | 0.003     |    |
| C3 (W.s/°C)                     | 0.015     |    |
| C4 (W.s/°C)                     | 0.15      |    |
| C5 (W.s/°C)                     | 1.5       |    |
| C6 (W.s/°C)                     | 3         | 5  |

## 5 Package and packing information

### 5.1 ECOPACK<sup>®</sup> packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

Figure 32. SO-16L package dimensions

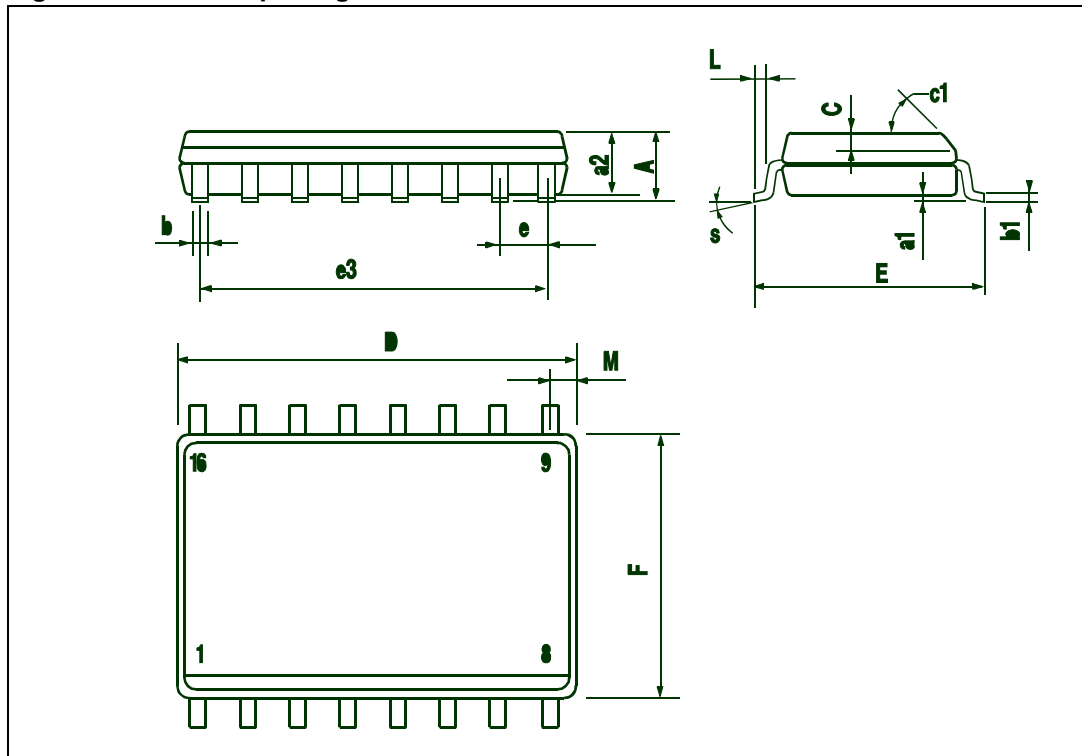


Table 17. SO-16L mechanical data

| DIM. | mm.        |      |       |
|------|------------|------|-------|
|      | Min.       | Typ. | Max.  |
| A    |            |      | 2.65  |
| a1   | 0.1        |      | 0.2   |
| a2   |            |      | 2.45  |
| b    | 0.35       |      | 0.49  |
| b1   | 0.23       |      | 0.32  |
| C    |            | 0.5  |       |
| c1   | 45° (typ.) |      |       |
| D    | 10.1       |      | 10.5  |
| E    | 10.0       |      | 10.65 |
| e    |            | 1.27 |       |
| e3   |            | 8.89 |       |
| F    | 7.4        |      | 7.6   |
| L    | 0.5        |      | 1.27  |
| M    |            |      | 0.75  |
| S    | 8° (max.)  |      |       |



## 6 Revision history

**Table 18. Document revision history**

| Date        | Revision | Changes          |
|-------------|----------|------------------|
| 03-May-2010 | 1        | Initial release. |

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**Наши контакты:**

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331